

View Online at <https://aerobasegroup.com/nsn/5980-01-384-4942>

**General Description:**

Gallium arsenide diode infrared source optically coupled t a silicon n-p-n phototransistor; 0.337 in. Maximum lg; 0.260 in. Maximum wd; 6 pin dip;

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

Yes - demil/mli

**Fiig:**

A23900